

Wireless readout

# MULTI-GIGABIT WIRELESS DATA TRANSFER FOR TRACKER READOUT SYSTEMS

H.K. Soltveit, A. Schöning, S. Dittmeier, D. Wiedner

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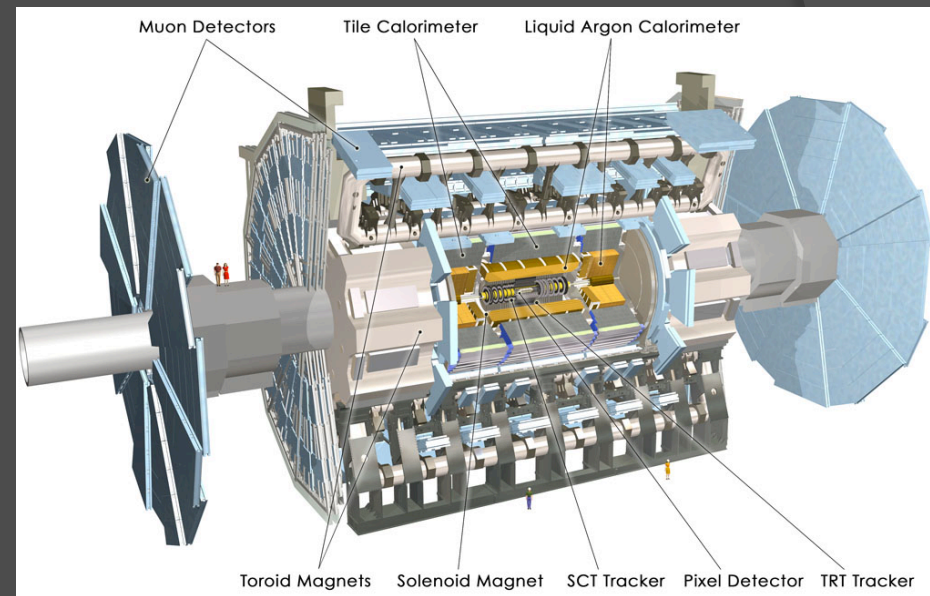
# OUTLINE

- ⦿ Motivation
- ⦿ Features of the 60GHz band
- ⦿ Proposed Readout Concept
- ⦿ Applied Technology
- ⦿ 60 GHz Transceiver Chip
- ⦿ Performance from Simulations
- ⦿ Summary and Outlook

# MOTIVATION

ATLAS Silicon Microstrip Tracker upgrade would require:

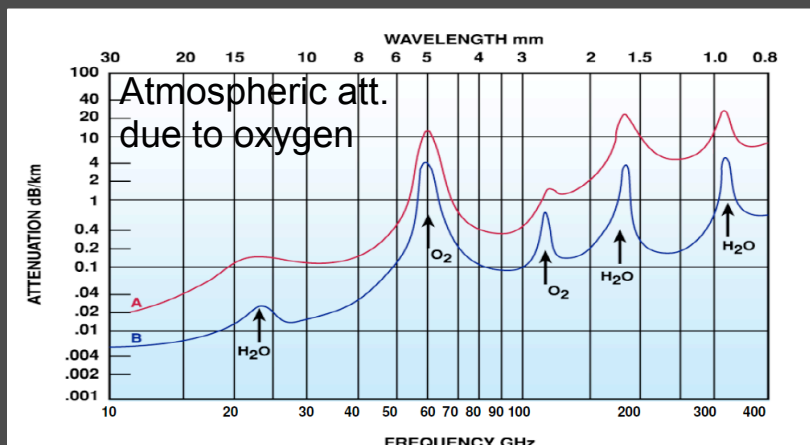
- Bandwidth of 100 Tb/s
  - 20 000 links at 5 Gb/s
- without increasing the
- Material budget
  - Power consumption
  - Space for services
- and in addition
- Contribute to the fast trigger decision



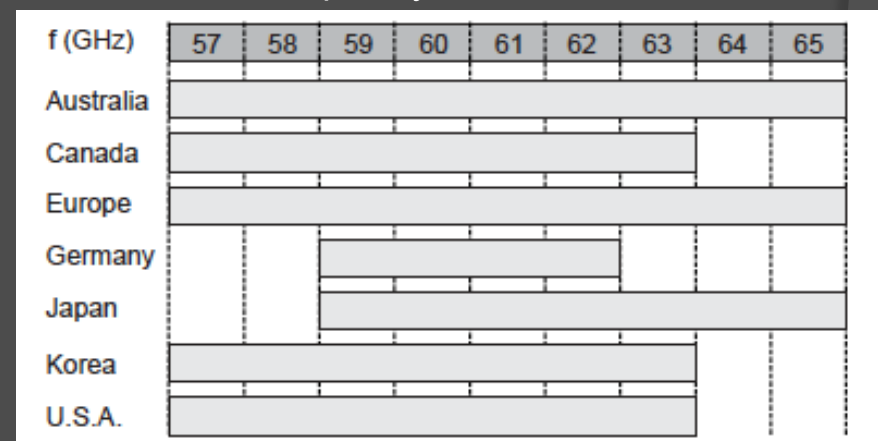
**Approach: Wireless Data Transfer using the 60 GHz band**

# Features of the 60 GHz band

- **Unlicensed Spectrum:** 4-9 GHz bandwidth available world-wide
- **Mostly unused:** Low interference probability
- **Security:** Attenuation through walls/silicon
  - Reuse of frequency
- **Can send Gigabits/s of data over short distance** (0-100m)
- **High frequency:** Small form factor
- **High transmit power:** 40 dBm EIRP (Effective Isotropic Radiated Power)
- **Placement:** High flexibility



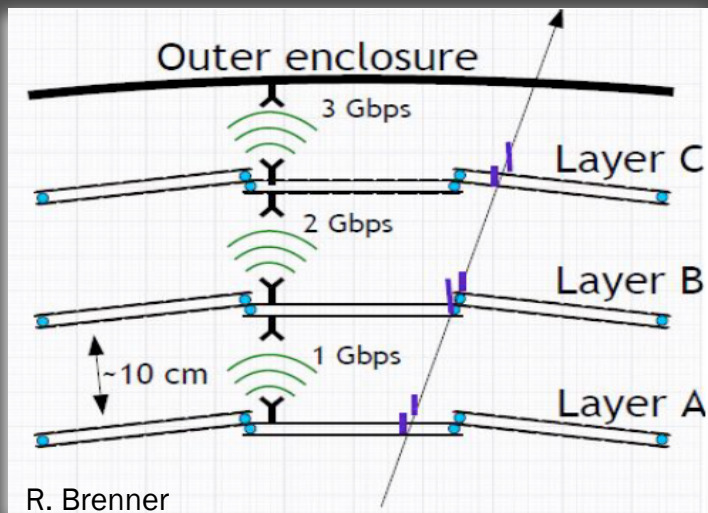
Available frequency band around the world.



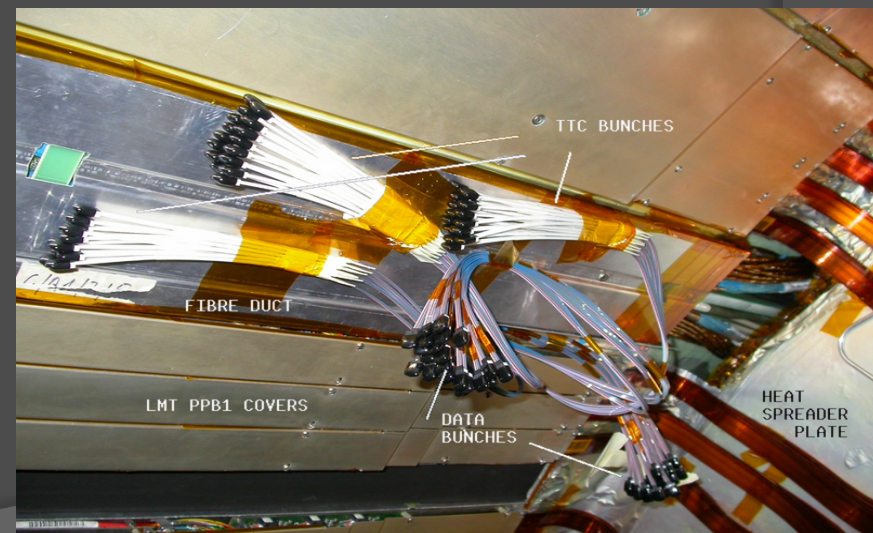
# Proposed Readout Concept

- Today the data are readout perpendicular to the particle path.
- Approach: Readout radially by sending the data through the layer(s) by wire/via connection, with an antenna on both sides.

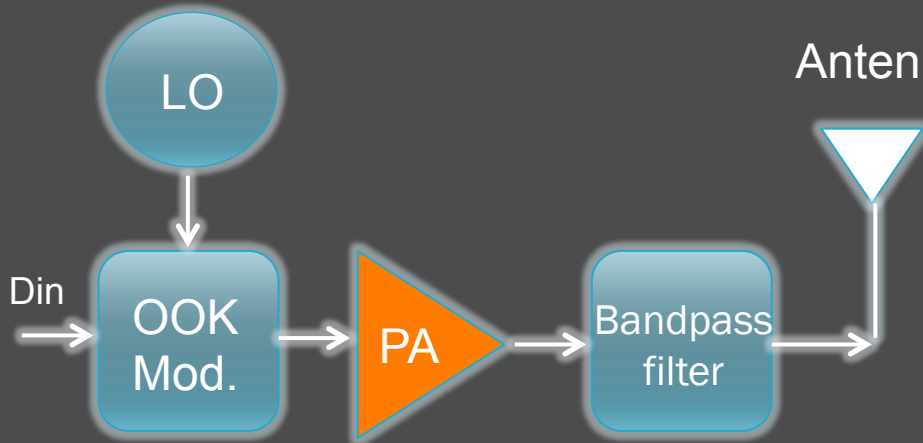
Readout path along particle path  
Helps Track Trigger



Less cables and Connectors  
Reduce Material Budget



# 60 GHz Transceiver Chip

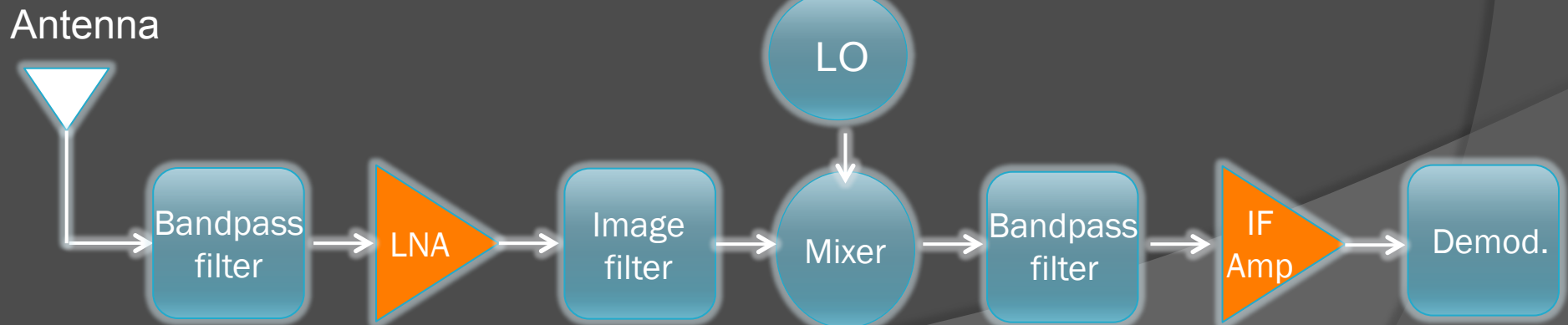


Antenna **Transmitter:**

- Deliver necessary output power
- High power efficiency
- High gain and stability

**Receiver:**

- Need Low Noise Amplifier (LNA)
- Balance gain, linearity and NF
- Low Power Dissipation



# System Specifications

System  $\text{SNR}_{\min}$  is determined by the Bit-Error-Rate (BER) of a given Modulation scheme.

For OOK:  $\text{BER} = 10^{-12} \rightarrow \text{SNR}_{\min} \approx 17\text{dB}$

$\text{Noisefloor} = -174\text{dBm} + 10 \log_{10}(9\text{G}) = -75\text{ dBm}$

$\text{NF}_{\text{tot}}$  chosen to be 9 dB

$S_{\text{RX}} = \text{Noisefloor} + \text{SNR}_{\min} + \text{NF}_{\text{tot}} = -49\text{ dBm}$

Minimum power level that the system can detect producing an acceptable signal to noise ratio at the output.

Specifications	Value
Frequency band	57-66 GHz
Bandwidth	<b>9 GHz</b>
Data Rate	<b>4.5 Gbps</b>
Modulation	OOK
Minimum sensitivity $S_{\text{rx}(\min)}$	- 49 dBm
Bit Error Rate (BER)	$10^{-12}$
Target Power consumption	<b>250 mW</b>
Transmission Range	10 cm (1m)

# Link-Budget

$$P_{RX} = P_{TX} + G_{TX} + G_{RX} - L_{TX} - PL(R) - L_{RX} - FM$$

$P_{RX}$  = RX Power (dBm)

$P_{TX}$  = TX Power (5 dBm)

$G_{TX}$  = Transmitter antenna gain (10 dBi)

$G_{RX}$  = Receiver antenna gain (10 dBi)

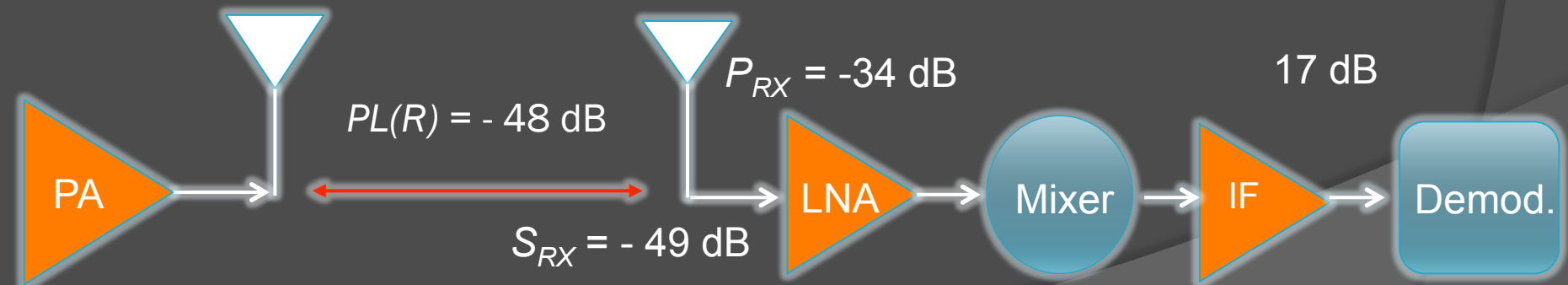
$L_{TX}$  = Transmitter losses (4 dB)

$L_{RX}$  = Receiver losses (4 dB)

FM = Fading Margin (3 dBm)

$PL(R)$  = Free space loss@1 m(10 cm)= 68 (48 dB)

System operating margin: 15 dB





# SiGe-HBT BiCMOS-8HP

- 130 nm Lithography based SiGe Bi-CMOS
- Advanced SiGe NPNs,  $W_e=120$  nm,  $f_t=200$  GHz,  $BV_{ceo}=1.8V$
- 130 nm CMOS FETs 1.5/2.5V
- High integration level
- Millimeter Wave Passives Elements
  - Resistors, Varactors, MOS and MIM caps, Inductors, Transmission-lines, Metal inductors, Coplanar Waveguide inductors and Microstrip Inductors

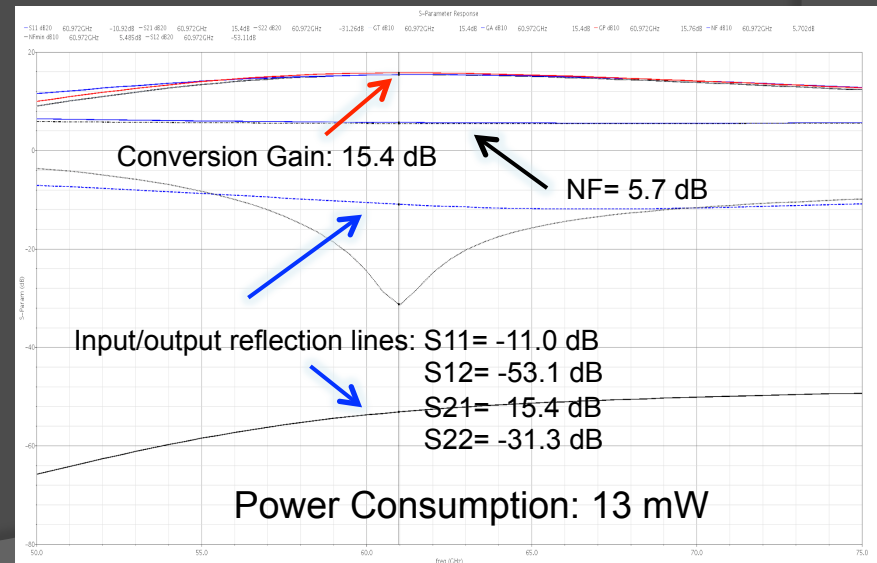
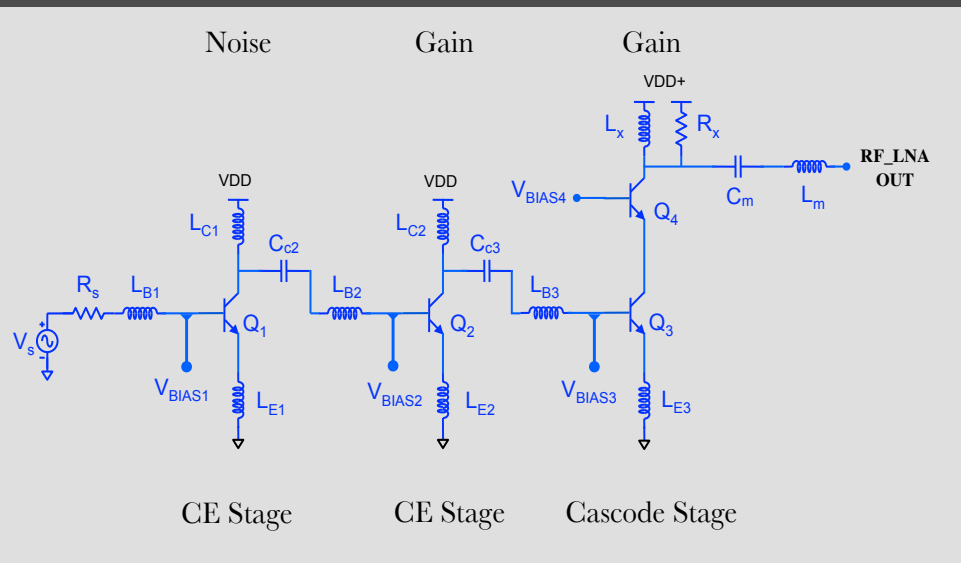
# Low Noise Amplifier (LNA)

- Sets the lower limit of the system
- Optimized for NF and Gain

- Matching of input and output
- Isolation between input and output

$$NF_{IN} = NF_1 + \frac{NF_2 - 1}{G_1} + \frac{NF_3 - 1}{G_1 G_2} + \frac{NF_4 - 1}{G_1 G_2 G_3} + \dots + \frac{NF_n - 1}{G_1 G_2 \dots G_{n-1}}$$

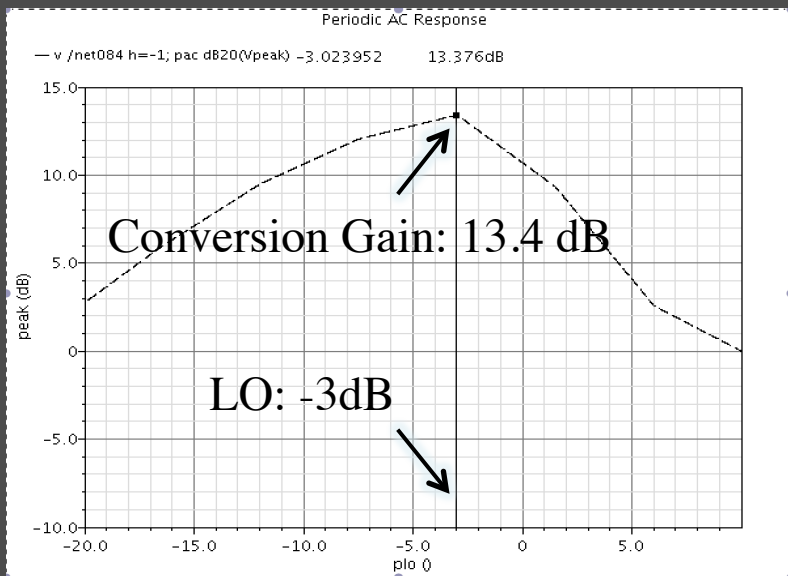
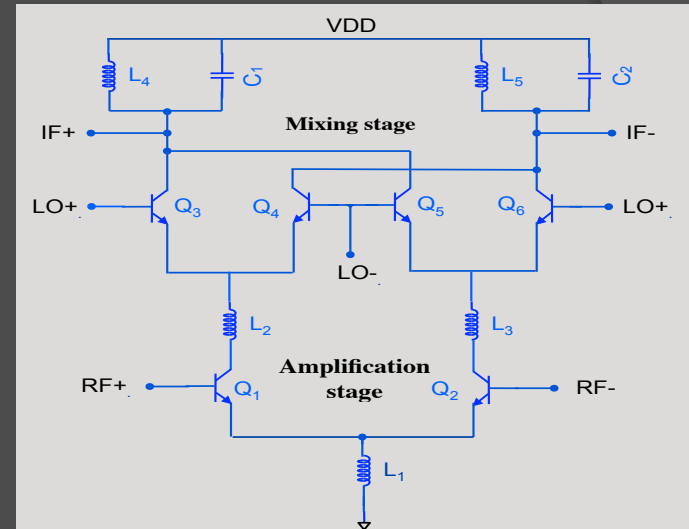
S-Parameter Respons, all @ 61 GHz



# Double Balanced Mixer

## Gilbert Cell structure

- Very good Isolation
- Harmonic suppression
- Immune to LO/RF feedthrough noise
- Differential structure
- Integrated on-chip

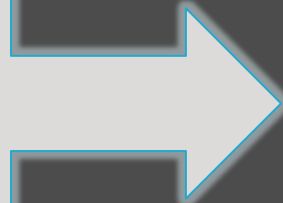


Noise: 9.5 dB  
Power consumption: 7 mW  
P1dB: -19 dB  
RF-LO: -150 dB  
RF-IF: -90 dB  
LO-IF: -100 dB  
LO-RF: -82 dB

# On-Off Keying Modulation

Modulation: OOK

- System bandwidth
- Efficiency
- Power Efficiency
- Sensitivity
- Complexity

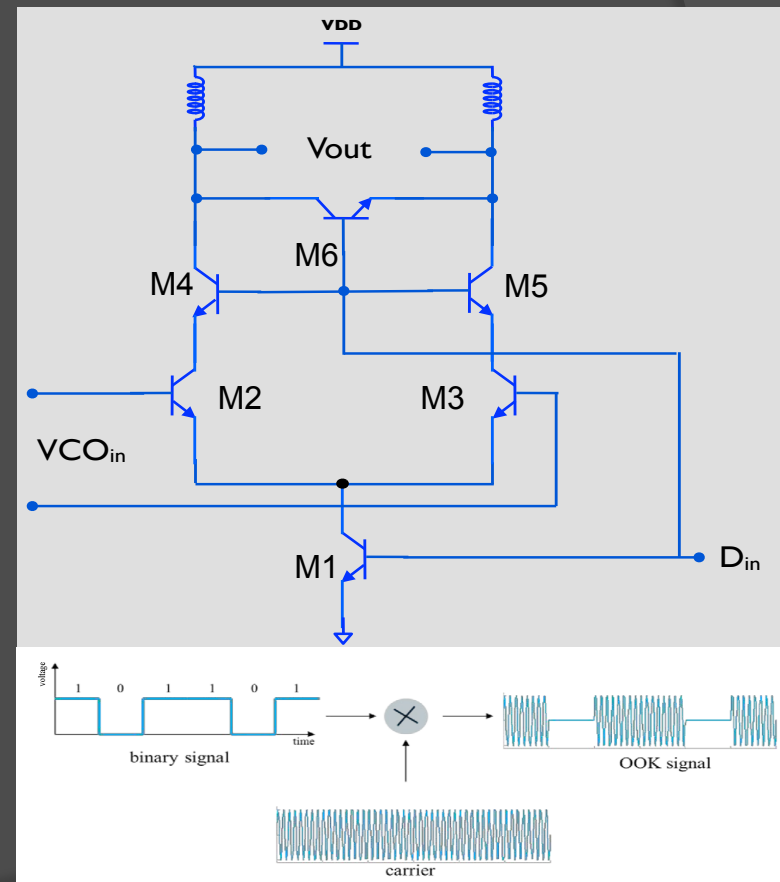


Low spectral efficiency: 0.5 bps/Hz

But

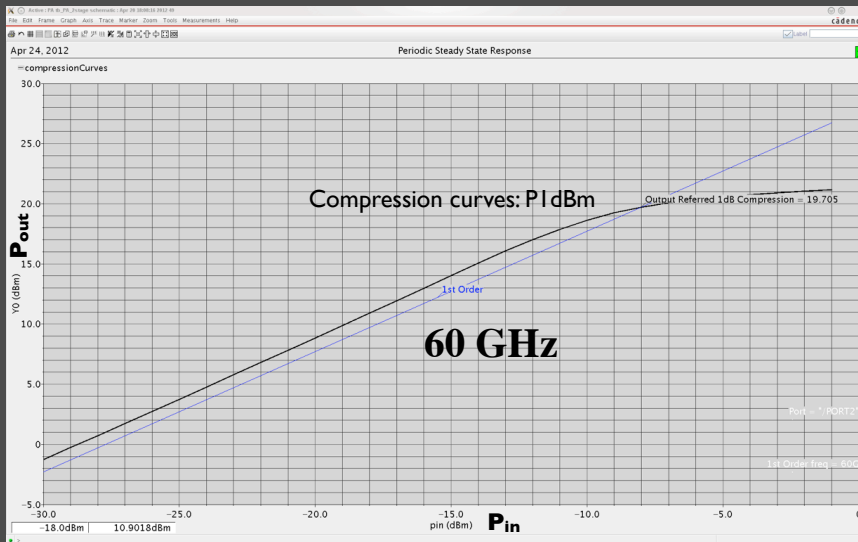
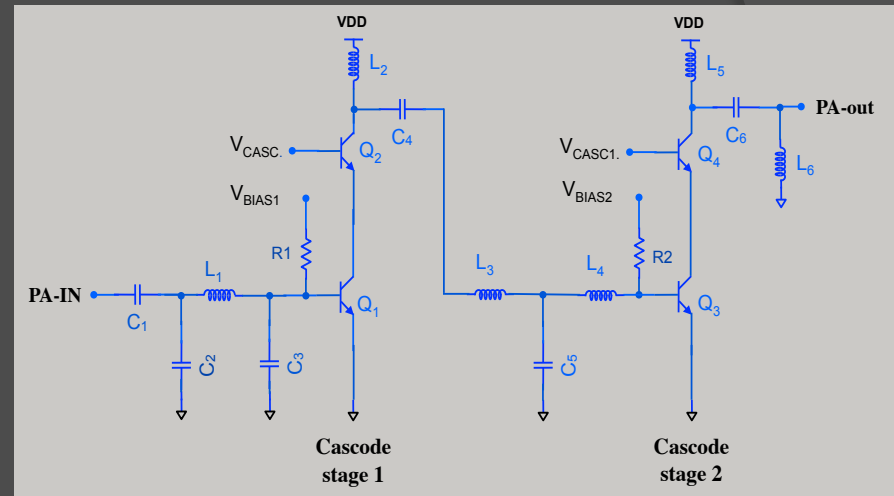
- Non-coherent demodulation
- Simple implementation
- Little power consumption

OOK scheme



# Power Amplifier (PA)

- Operation class AB
- Provide the required power level
- Drive the antenna



Compression Point: 20 dBm  
 Reverse Isolation: - 65 dB  
 Power added efficiency: 20 %  
 Power consumption: 150 mW

# Preliminary Power Estimate

- Low Noise Amplifier: 13 mW
- Gilbert Mixer: 7 mW
- Local Oscillator: 20 mW
- Intermediate Amplifier: 10 mW
- Modulation Scheme: 20 mW
- Demodulation Scheme: 20 mW
- Power Amplifier: 150 mW

Power Consumption: 240 mW

# Summary and Outlook

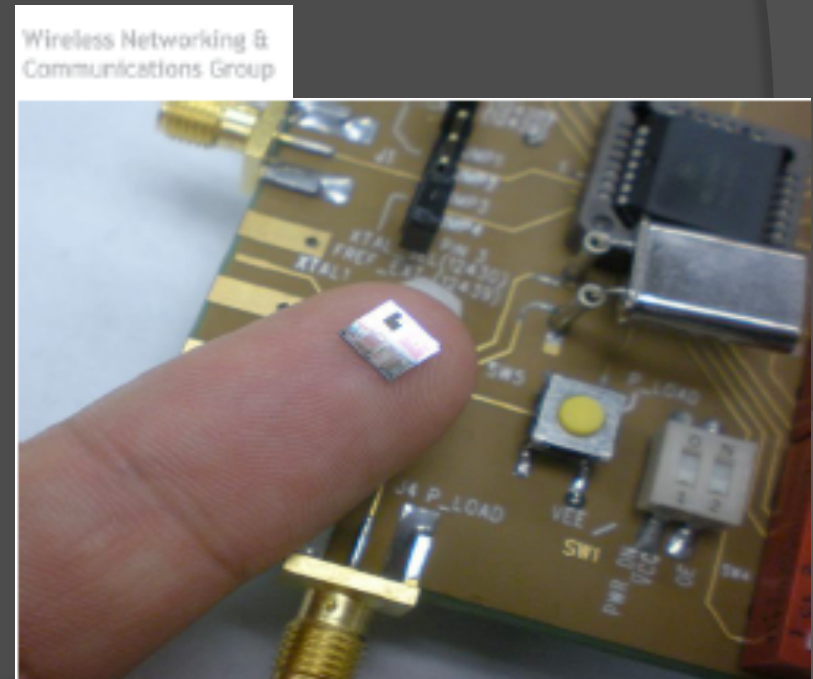
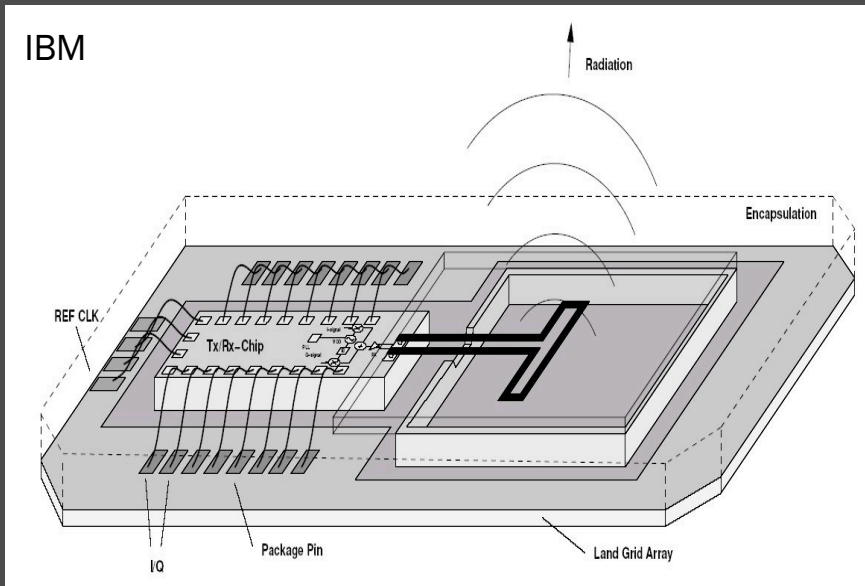
- ⦿ Potential wireless Readout scheme for the inner tracker proposed
  - Has the bandwidth required for real time readout for fast trigger data
- ⦿ Focused on the 60 GHz band due to its huge amount of bandwidth
- ⦿ Performance of key blocks shown from simulations
- ⦿ Integrate all individual blocks to a fully integrated Transceiver
- ⦿ Determine efficient and low-cost antenna solution
- ⦿ Forseen submission 4<sup>rd</sup> quarter of 2014

# BACKUP SLIDES



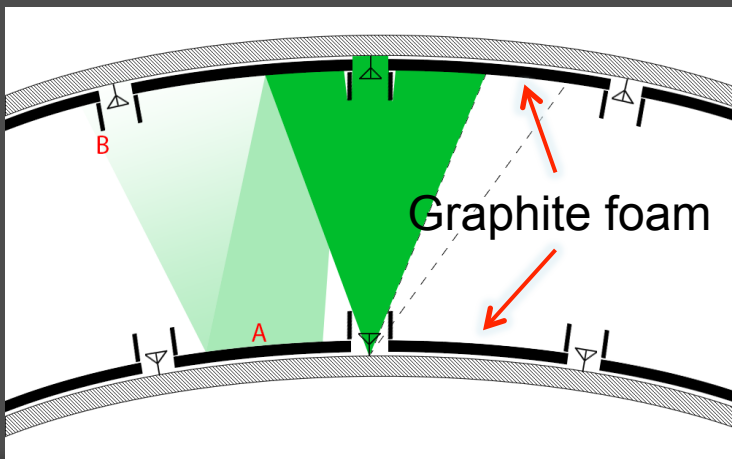
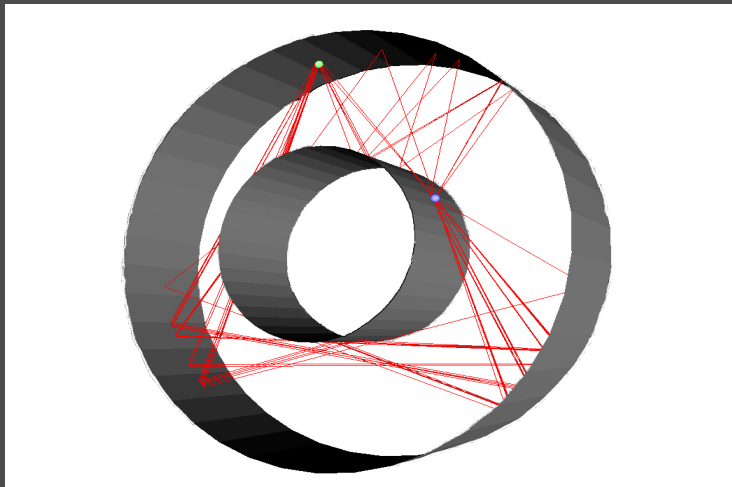
# On-chip Antenna

- Millimeter-Wave signals have small wavelengths at 60 GHz (5mm)
- Possible to integrate receive and transmit antenna(s) on chip.
- Multiple metal layers on ICs available
- Can be used to fabricate mm-wave antennas.
- Eliminate cable/connectors loss



# Crosstalk evaluation

- Simulations show that reflections will introduce crosstalk



## To decrease crosstalk:

- Shielding: Graphite foam
- Use antenna with high directivity
- Polarisation
- Frequency channeling

